VG7050EBN

Product name VG7050EBN Product code / Ordering code

644.531300MHz CJGHCZ

X1G0045510014xx

Please refer to the 8.Packing information about xx (last 2 digits)

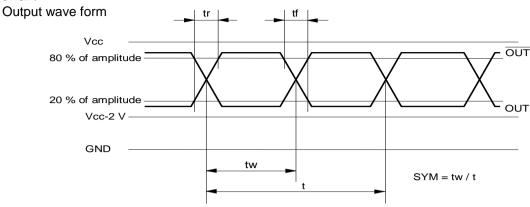
Output waveform LV-PECL Pb free / Complies with EU RoHS directive Reference weight Typ.166mg

1.Absolute maximum ratings							
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions / Remarks	
Maximum supply voltage	Vcc-GND	-0.3	-	+4	V	-	
Storage temperature	T_stg	-55	-	+125	°C	-	
Input voltage	Vin	-0.3	-	Vcc+0.3	V	Vc pin	

2.Specifications(characteristics)							
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions / Remarks	
Output frequency	fO		644.5313		MHz		
Supply voltage	Vcc	2.97	3.3	3.63	V	-	
Control voltage	Vc	0.3	1.65	3	V	Vc=1.65V+/-1.35V	
Operating temperature	T_use	-40	-	+85	°C	-	
Frequency tolerance	f_tol	-50	-	+50	x10⁻ ⁶	includes 10 years aging	
Current consumption	lcc	-	-	90	mA	L_ECL = 50Ω	
Disable current	I_dis	-	-	-	mA	-	
Frequency control range	f_cont	+/-150	-	-	x10 ⁻⁶	-	
Absolute pull range	APR	+/-100			x10 ⁻⁶	-	
Modulation characteristics	BW	10	-	-	kHz	+/-3 dB	
Input resistance	Rin	5000	-	-	kΩ	DC Level	
Frequency change polarity	-					Positive polarity	
Symmetry	SYM	45	-	55	%	at outputs crossing point	
Output voltage	V _{OH}	Vcc-1.025	-	-	V	-	
	V _{OL}	-	-	Vcc-1.62	V	-	
Output load condition	L_ECL	-	50	-	Ω	Outputs terminated to Vcc-2.0V	
Input voltage	V _{IH}	70%Vcc	-	-	V	OE pin	
	V _{IL}	-	-	30%Vcc	V	OE pin	
Rise time	tr	-	-	0.4	ns	20 % to 80 % of amplitude	
Fall time	tf	-	-	0.4	ns	20 % to 80 % of amplitude	
Start-up time	t_str	-	-	10	ms	-	
Phase noise		-	-90	-	dBc/Hz	Offset 100Hz	
		-	-107	-	dBc/Hz	Offset 1kHz	
	F_{CN}	-	-114	-	dBc/Hz	Offset 10kHz	
		-	-118	-	dBc/Hz	Offset 100kHz	
		-	-137	-	dBc/Hz	Offset 1MHz	
Phase jitter	t _{PJ}	-	0.2	-	ps	Offset Frequency: 12kHz to 20MHz	
Frequency aging	f_aging	-	-	-	x10 ⁻⁶	Included in frequency tolerance	

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3. Timing chart



4.Test circuit

1) Condition

- (1) Oscilloscope
 - Bandwidth should be 5 times higher than DUT's output frequency.
 - Probe ground should be placed closely from test point and lead length should be as short as possible.
- (2) By-pass capacitor (approx. 0.01 mF ~ 0.1 mF) should be placed closely between Vcc and GND.

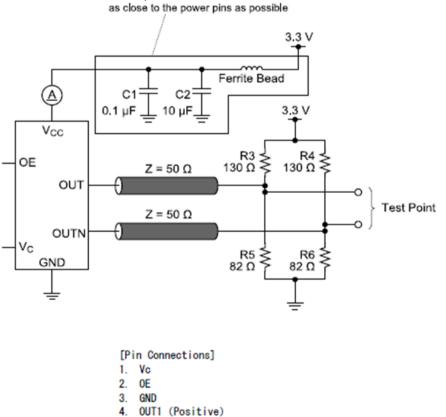
Please place them on the device side of the PCB

(3) Use the current meter whose internal impedance value is small.

(4) Power supply

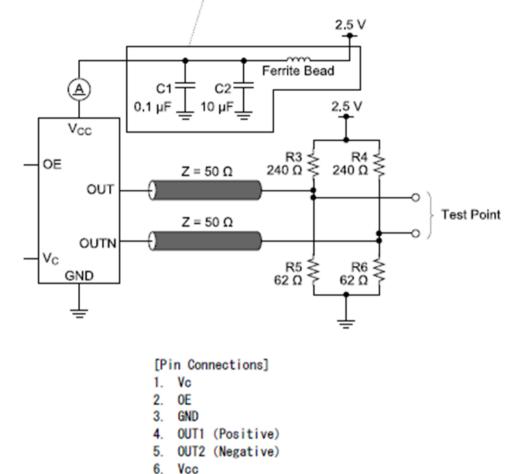
- Start up time(0 V→90 %Vcc)of power source should be more than 150us.
- Impedance of power supply should be as low as possible.

2) Vcc = 3.3V

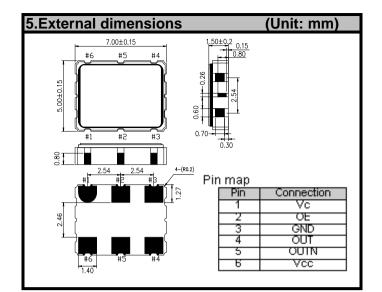


- 5. OUT2 (Negative) 6.
 - Vcc

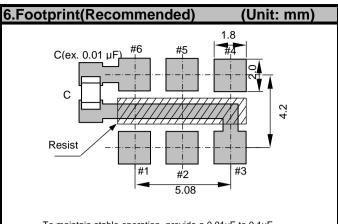
3) Vcc = 2.5V



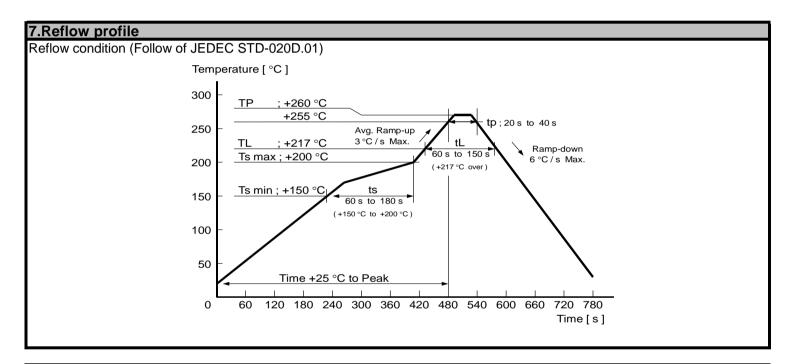
Please place them on the device side of the PCB as close to the power pins as possible



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To maintain stable operation, provide a 0.01uF to 0.1uF by-pass capacitor at a location as near as possible to the power source terminal of the crystal product (between Vcc - GND).

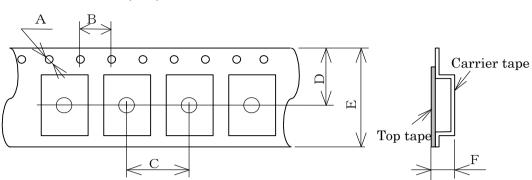


8.Packing	<u>g informa</u>	tion					
[1]Produc	t number la	number last 2 digits code(xx) description		The recommended code is "00"			
	X1G0045	510014xx					
	Code	Condition	Code	Condition			
	00	1000pcs / Reel	12	250pcs / Reel			
	01	Any Q'ty vinyl bag(Tape cut)	13	500pcs / Reel			
	11	Any Q'ty / Reel					

Unit: mm

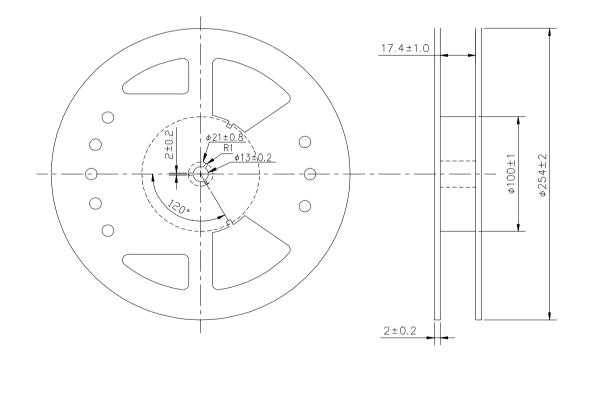
2] Taping specification Subject to EIA-481 & IEC-60286

(1) Tape dimensionsMaterial of the Carrier Tape : PSMaterial of the Top Tape : PET+PE



Symbol	А	В	С	D	Е	F
Value	Φ1.5	4	8	9.25	16	2.3

(2) Reel dimensions Center material : PS Material of the Reel : PS



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